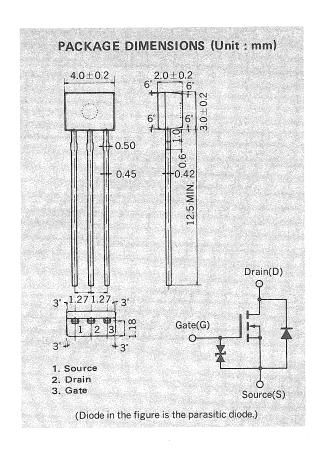
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P1 98.2



# MOS FIELD EFFECT TRANSISTOR 2SK1656

# N-CHANNEL MOS FET FOR SWITCHING



The 2SK1656 is an N-channel vertical type MOS FET which can be driven by 2.5 V power supply.

As the MOS FET is low Gate Leakage Current, it is suitable for appliances including Filter Circuit.

#### **FEATURES**

- Directly driven by ICs having a 3 V power supply.
- Has low Gate Leakage Current
   I<sub>GSS</sub> = ±5 nA MAX. @ V<sub>GS</sub> = ±3.0 V

#### QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

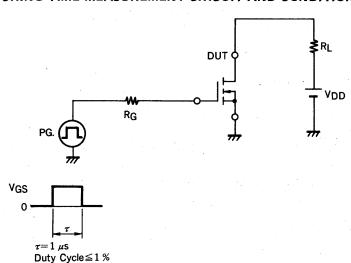
# ABSOLUTE MAXIMUM RATINGS ( $T_a = 25$ °C)

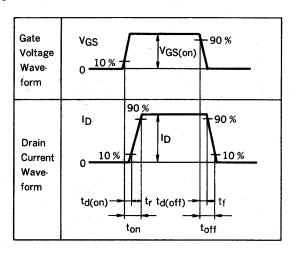
PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	V <sub>DSS</sub>	30	V	V <sub>GS</sub> = 0
Gate to Source Voltage	VGSS	±7	V	V <sub>DS</sub> = 0
Drain Current	ID(DC)	±100	· mA	
Drain Current	I <sub>D</sub> (pulse)	±200	mA	PW $\leq$ 10 ms, Duty Cycle $\leq$ 50 %
Total Power Dissipation	PT	250	mW	
Channel Temperature	T <sub>ch</sub>	150	°C	
Operating Temperature	T <sub>opt</sub>	-55 to +80	°C	
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C	

### ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

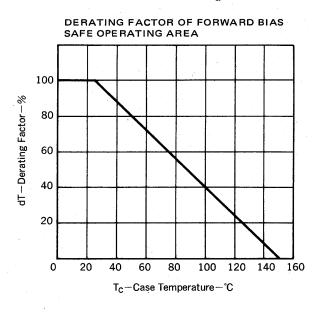
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PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Cut-off Current	IDSS			10	μΑ	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0	
Gate Leakage Current	IGSS			±5.0	nA	$V_{GS} = \pm 3.0 \text{ V, } V_{DS} = 0$	
Gate Cut-off Voltage	VGS(off)	0.9	1.2	1.5	V	V <sub>DS</sub> = 3.0 V, I <sub>D</sub> = 1 mA	
Forward Transfer Admittance	ly <sub>fs</sub> i	20	40		mS	V <sub>DS</sub> = 3.0 V, I <sub>D</sub> = 0.3 A	
Drain to Source On-State Resistance	R <sub>DS</sub> (on)1		25	45	Ω	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 0.3 A	
Drain to Source On-State Resistance	R <sub>DS(on)2</sub>		18	25	Ω	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 0.3 A	
Input Capacitance	Ciss		15		pF		
Output Capacitance	Coss		10		pF	V <sub>DS</sub> = 3.0 V, V <sub>GS</sub> = 0, f = 1 MHz	
Feedback Capacitance	C <sub>rss</sub>		1,5		pF		
Turn-On Delay Time	td(on)		50	1	ns		
Rise Time	t <sub>r</sub>		23		ns	V <sub>DD</sub> = 3.0 V, I <sub>D</sub> = 10 mA	
Turn-Off Delay Time	<sup>t</sup> d(off)		34		ns	$V_{GS(on)}$ = 3 V, $R_G$ = 10 $\Omega$	
Fall Time	tf		43		ns		

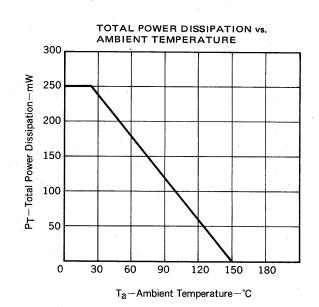
#### SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS

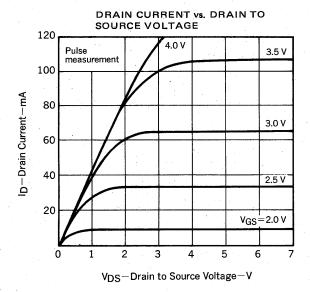


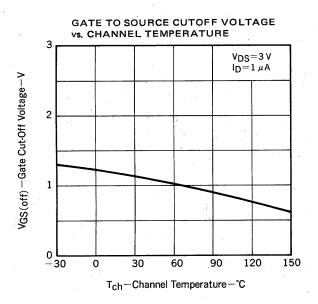


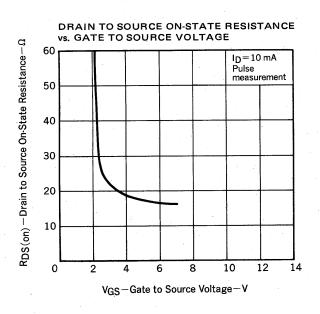
## TYPICAL CHARACTERISTICS (Ta = 25 °C)

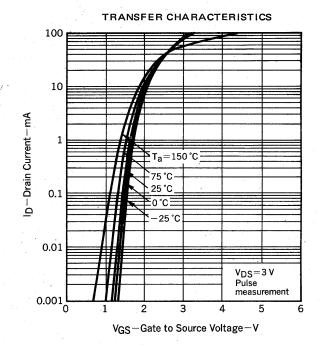


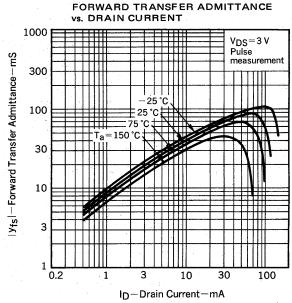


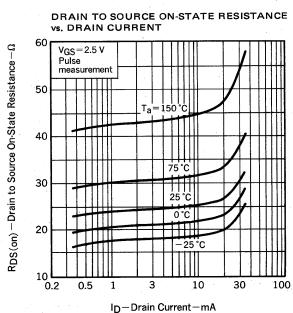


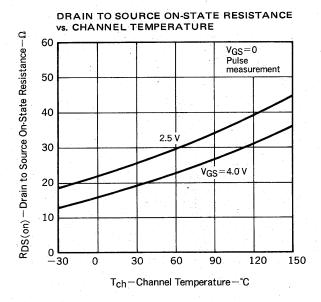


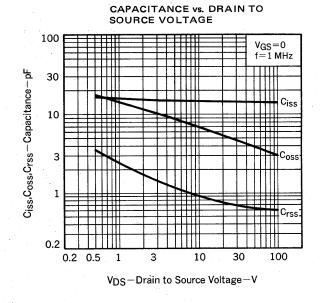


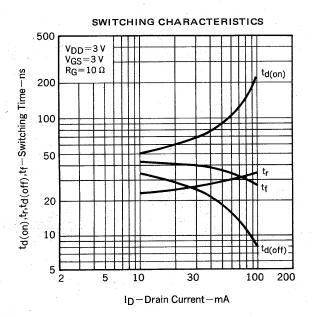


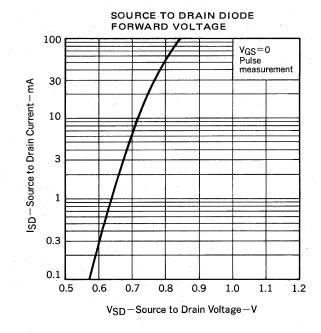












#### **RECOMMENDED SOLDERING CONDITIONS**

Mounting of this product by soldering should be done under the following conditions.

Please consult our representatives about soldering methods and conditions other than these.

#### **SURFACE MOUNT TYPE**

For details of the recommended soldering conditions, see the information document "SMT MANUAL" (IEI-1207).

Soldering Method	Soldering Conditions	Symbol for Recommended Conditions	
Infrared Reflow	Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none*	IR30-00	
Vapor Phase Soldering	Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none*	VP15-00	
Wave Soldering	Soldering bath temp.: below 260 °C Soldering time: within 10 sec Soldering times: 1, Days limitation: none*	WS60-00	

<sup>\*:</sup> Stored days under storage conditions at 25 °C and below 65 % R,H, after the dry-pack has been opened. Note 1 Combination of soldering methods should be avoided.

(MEMO)

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Application examples recomended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and

Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Automotive and Transportation equipment, Communication equipment (trunk line), Train and Special:

Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime

systems etc.